

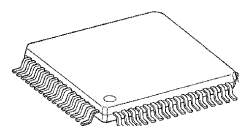
CMOS 8-Bit Microcontroller

TMP86P820U/F

The TMP86P820 is a OTP type MCU which includes 8 Kbyte One-time PROM. It is a pin compatible with a mask ROM product of the TMP86C420/820. Writing the program to built-in PROM, the TMP86P820 operates as the same way as the TMP86C420/820. Using the Adapter socket, you can write and verify the data for the TMP86P820 with a general-purpose PROM programmer same as TC571000D/AD.

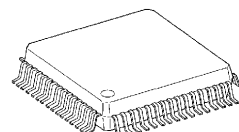
Product No.	OTP	RAM	Package	Adapter Socket
TMP86P820U	8 K × 8 bits	256 × 8 bits	P-LQFP64-1010-0.50	BM11162
TMP86P820F			P-QFP64-1414-0.80A	BM11163

P-LQFP64-1010-0.50



TMP86P820U

P-QFP64-1414-0.80A



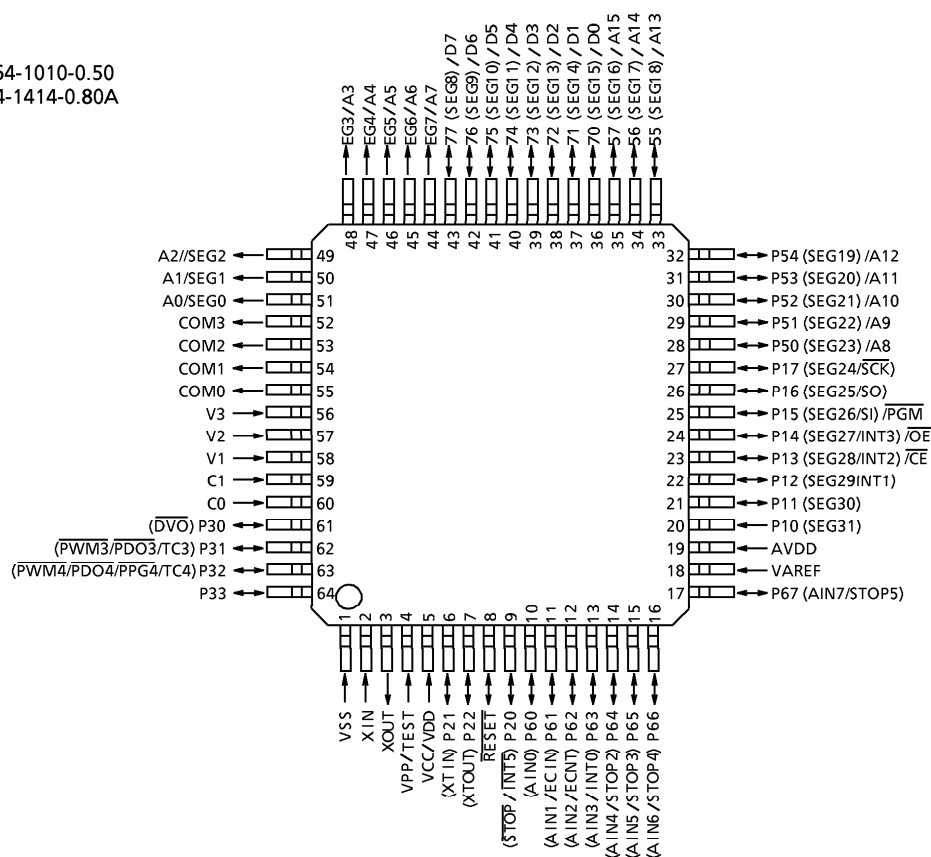
TMP86P820F

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Pin Assignments (Top View)

P-LQFP64-1010-0.50
P-QFP64-1414-0.80A



Pin Functions

The TMP86P820 has MCU mode and PROM mode.

(1) MCU mode

In the MCU mode, the TMP86P820 is a pin compatible with the TMP86C420/820 (Make sure to fix the TEST pin to low level).

(2) PROM mode

Pin Name	Input/Output	Functions	Pin Name (MCU mode)
A15 to A8	Input	Input of Memory address for program	P57 to P50
A7 to A0			SEG7 to SEG0
D7 to D0	I/O	Input/Output of Memory data for program	P77 to P70
$\overline{CE}$	Input	Chip enable	P13
$\overline{OE}$		Output enable	P14
PGM		Program control	P15
VPP	Power supply	+ 12.75 V/5 V (Power supply of program)	TEST
VCC, AVDD		+ 6.25 V/5 V	VDD, AVDD
GND, VAREF		0 V	VSS, VAREF
P11, P21	I/O	PROM mode setting pin. Fix to high.	
P10, P22, P20, P61		PROM mode setting pin. Fix to low.	
RESET			
P64, P65, P67	Output	Output pin for PROM operation test. Open or release.	
P17, P16, P12	I/O	Open	
P66, P63 to P62, P60			
P33 to P30			
COM3 to COM0			
V3 to V1			
C1, C0			
XIN	Input	Self oscillation with resonator (8 MHz).	
XOUT	Output		

Note: No pin is applied to A16 input.

Operation

This section describes the functions and basic operational blocks of TMP86P820.

The TMP86P820 has PROM in place of the mask ROM which is included in the TMP86C420/820.

The configuration and function are the same as the mask ROM products.

In addition, TMP86P820 operates as the single clock mode when releasing reset.

When using the dual clock mode, oscillate a low-frequency clock by SET. XTEN command at the beginning of program.

1. Operating Mode

The TMP86P820 has MCU mode and PROM mode.

1.1 MCU Mode

The MCU mode is set by fixing the TEST/VPP pin to the low level. (TEST/VPP pin cannot be used open because it has no built-in pull-down resistor).

1.1.1 Program Memory

The TMP86P820 has a 8 Kbyte built-in one time PROM (addresses E000 to FFFF_H in the MCU mode, addresses 0000 to 1FFF_H in the PROM mode).

When using TMP86P820 for evaluation of mask ROM products, the program is written in the program storing area shown in Figure 1-1.

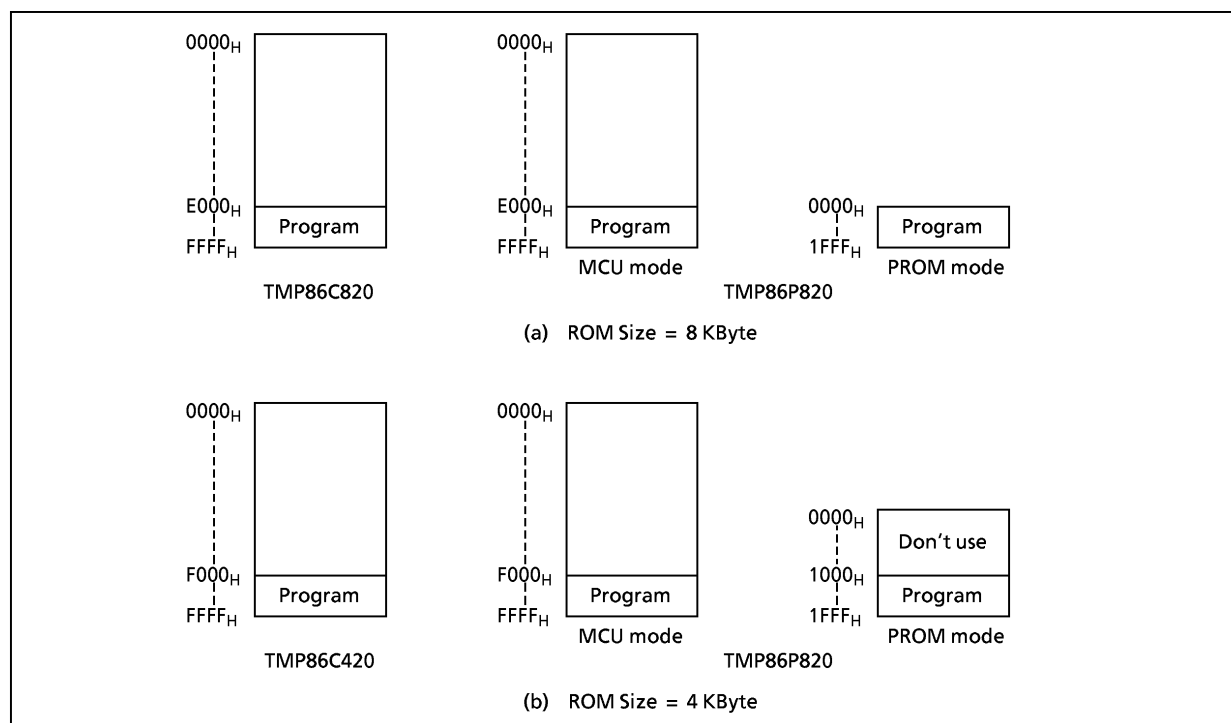


Figure 1-1. Program Memory Area

Note: The area that is not in use should be set data to FFH, or a general-purpose PROM programmer should be set only in the program memory area to access.

Electrical Characteristics

Absolute Maximum Ratings

(V_{SS} = 0 V)

Parameter	Symbol	Pins	Rating	Unit
Supply Voltage	V _{DD}		– 0.3 to 6.5	V
Program Voltage	V _{PP}	TEST/V _{PP}	– 0.3 to 13.0	
Input Voltage	V _{IN}		– 0.3 to V _{DD} + 0.3	
Output Voltage	V _{OUT1}		– 0.3 to V _{DD} + 0.3	
Output Current (Per 1 pin)	I _{OUT1}	P3, P6 Port	– 1.8	mA
	I _{OUT2}	P1, P2, P5, P6, P7 Port	3.2	
	I _{OUT3}	P3 Port	30	
Output Current (Total)	ΣI _{OUT1}	P1, P2, P5, P6, P7 Port	60	
	ΣI _{OUT2}	P3 Port	80	
Power Dissipation [T _{opr} = 85°C]	PD		350	mW
Soldering Temperature (time)	T _{sld}		260 (10 μ)	°C
Storage Temperature	T _{stg}		– 55 to 125	
Operating Temperature	T _{opr}		– 40 to 85	

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Condition	($V_{SS} = 0\text{ V}$, $T_{opr} = -40\text{ to }85^{\circ}\text{C}$)
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Parameter	Symbol	Pins	Condition		Min	Max	Unit
Supply Voltage	V _{DD}		fc = 16 MHz	NORMAL1, 2 mode	4.5	5.5	V
				IDLE0, 1, 2 mode			
			fc = 8 MHz	NORMAL1, 2 mode	2.7		
				IDLE0, 1, 2 mode			
			fc = 4.2 MHz	NORMAL1, 2 mode	1.8		
				IDLE0, 1, 2 mode			
			fs = 32.768 kHz	SLOW1, 2 mode			
				SLEEP0, 1, 2 mode			
	STOP mode						
Input high Level	V _{IH1}	Except Hysteresis input	V _{DD} ≥ 4.5 V		V _{DD} × 0.70	V _{DD}	
	V _{IH2}	Hysteresis input			V _{DD} × 0.75		
	V _{IH3}		V _{DD} < 4.5 V	V _{DD} × 0.90			
Input low Level	V _{IL1}	Except Hysteresis input	V _{DD} ≥ 4.5 V		0	V _{DD} × 0.30	
	V _{IL2}	Hysteresis input				V _{DD} × 0.25	
	V _{IL3}		V _{DD} < 4.5 V	V _{DD} × 0.10			
Clock Frequency	fc	XIN, XOUT	V _{DD} = 1.8 to 5.5 V		1.0	4.2	MHz
			V _{DD} = 2.7 to 5.5 V			8.0	
			V _{DD} = 4.5 to 5.5 V			16.0	
	fs	XTIN, XTOUT			30.0	34.0	kHz

Note: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

DC Characteristics

(V_{SS} = 0 V, Topr = – 40 to 85°C)

Parameter	Symbol	Pins	Condition	Min	Typ.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis input		–	0.9	–	V
Input Current	I _{IN1}	TEST	V _{DD} = 5.5 V, V _{IN} = 5.5 V/0 V	–	–	± 2	μA
	I _{IN2}	Sink Open Drain, Tri-state					
	I _{IN3}	RESET, STOP					
Input Resistance	R _{IN2}	RESET Pull-Up		100	220	450	kΩ
Output Leakage Current	I _{LO}	Sink Open Drain, Tri-state	V _{DD} = 5.5 V, V _{OUT} = 5.5 V/0 V	–	–	± 2	μA
Output High Voltage	V _{OH2}	C-MOS, Tri-st Port	V _{DD} = 4.5 V, I _{OH} = – 0.7 mA	4.1	–	–	V
Output Low Voltage	V _{OL}	Except XOUT and P3 Port	V _{DD} = 4.5 V, I _{OL} = 1.6mA	–	–	0.4	
Output Low Current	I _{OL}	High Current Port (P3 Port)	V _{DD} = 4.5 V, V _{OL} = 1.0 V	–	20	–	mA
Supply Current in NORMAL 1, 2 mode	V _{DD}		V _{DD} = 5.5 V V _{IN} = 5.3/0.2 V f _c = 16 MHz f _s = 32.768 kHz	–	7.5	9	
Supply Current in IDLE 0, 1, 2 mode				–	5.5	6.5	
Supply Current in SLOW 1 mode			V _{DD} = 3.0 V V _{IN} = 2.8 V/0.2 V f _s = 32.768 kHz LCD driver is not enable.	–	18	42	μA
Supply Current in SLEEP 1 mode				–	16	25	
Supply Current in SLEEP 0 mode				–	12	20	
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V	–	0.5	10	

Note 1: Typical values show those at Topr = 25°C, V_{DD} = 5 V

Note 2: Input current (I_{IN1}, I_{IN2}); The current through pull-up or pull-down resistor is not included.

Note 3: I_{DD} does not include I_{REF} current.

Note 4: The supply currents of SLOW 2 and SLEEP 2 modes are equivalent to IDLE 0, 1, 2.

AD Conversion Characteristics

(V_{SS} = 0.0 V, 4.5 V ≤ V_{DD} ≤ 5.5 V, Topr = -40 to 85°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Analog Reference Voltage	V _{AREF}		A _{VDD} - 1.0	—	A _{VDD}	V
Power Supply Voltage of Analog Control Circuit	A _{VDD}		V _{DD}			
Analog Reference Voltage Range (Note 4)	△V _{AREF}		3.5	—	—	
Analog Input Voltage	V _{AIN}		V _{SS}	—	V _{AREF}	
Power Supply Current of Analog Reference Voltage	I _{REF}	V _{DD} = A _{VDD} = V _{AREF} = 5.5 V V _{SS} = 0.0 V	—	0.6	1.0	mA
Non linearity Error		V _{DD} = A _{VDD} = 5.0 V, V _{SS} = 0.0 V V _{AREF} = 5.0 V	—	—	± 1	LSB
Zero Point Error			—	—	± 1	
Full Scale Error			—	—	± 1	
Total Error			—	—	± 2	

(V_{SS} = 0.0 V, 2.7 V ≤ V_{DD} < 4.5 V, Topr = -40 to 85°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Analog Reference Voltage	V _{AREF}		A _{VDD} - 1.0	—	A _{VDD}	V
Power Supply Voltage of Analog Control Circuit	A _{VDD}		V _{DD}			
Analog Reference Voltage Range (Note 4)	△V _{AREF}		2.5	—	—	
Analog Input Voltage	V _{AIN}		V _{SS}	—	V _{AREF}	
Power Supply Current of Analog Reference Voltage	I _{REF}	V _{DD} = A _{VDD} = V _{AREF} = 4.5 V V _{SS} = 0.0 V	—	0.5	0.8	mA
Non linearity Error		V _{DD} = A _{VDD} = 2.7 V, V _{SS} = 0.0 V V _{AREF} = 2.7 V	—	—	± 1	LSB
Zero Point Error			—	—	± 1	
Full Scale Error			—	—	± 1	
Total Error			—	—	± 2	

(V_{SS} = 0.0 V, 2.0 V ≤ V_{DD} < 2.7 V, Topr = -40 to 85°C) Note 5(V_{SS} = 0.0 V, 1.8 V ≤ V_{DD} < 2.0 V, Topr = -10 to 85°C) Note 5

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Analog Reference Voltage	V _{AREF}		A _{VDD} - 0.9	—	A _{VDD}	V
Power Supply Voltage of Analog Control Circuit	A _{VDD}		V _{DD}			
Analog Reference Voltage Range (Note 4)	ΔV _{AREF}	1.8 V ≤ V _{DD} < 2.0 V	1.8	—	—	
		2.0 V ≤ V _{DD} < 2.7 V	2.0	—	—	
Analog Input Voltage	V _{AIN}		V _{SS}	—	V _{AREF}	
Power Supply Current of Analog Reference Voltage	I _{REF}	V _{DD} = A _{VDD} = V _{AREF} = 2.7 V V _{SS} = 0.0 V	—	0.3	0.5	mA
Non linearity Error		V _{DD} = A _{VDD} = 1.8 V, V _{SS} = 0.0 V V _{AREF} = 1.8 V	—	—	± 2	LSB
Zero Point Error			—	—	± 2	
Full Scale Error			—	—	± 2	
Total Error			—	—	± 4	

Note 1: The total error includes all errors except a quantization error, and is defined as a maximum deviation from the ideal conversion line.

Note 2: Conversion time is different in recommended value by power supply voltage.
About conversion time, please refer to "2.10.2 Register Framing".

Note 3: Please use input voltage to AIN input Pin in limit of V_{AREF} - V_{SS}.
When voltage of range outside is input, conversion value becomes unsettled and gives affect to other channel conversion value.

Note 4: Analog Reference Voltage Range: ΔV_{AREF} = V_{AREF} - V_{SS}

Note 5: When AD is used with V_{DD} < 2.7 V, the guaranteed temperature range varies with the operating voltage.

AC Characteristics

(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, Topr = – 40 to 85°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Machine Cycle Time	tcy	NORMAL 1, 2 mode	0.25	–	4	μ s
		IDLE 1, 2 mode				
		SLOW 1, 2 mode	117.6	–	133.3	
		SLEEP 1, 2 mode				
High Level Clock Pulse Width	twcH	For external clock operation (XIN input)	–	31.25	–	ns
Low Level Clock Pulse Width	twcL	fc = 16 MHz				
High Level Clock Pulse Width	twcH	For external clock operation (XTIN input)	–	15.26	–	μ s
Low Level Clock Pulse Width	twcL	fc = 32.768 kHz				

(V_{SS} = 0 V, V_{DD} = 2.7 to 4.5 V, Topr = – 40 to 85°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Machine Cycle Time	tcy	NORMAL 1, 2 mode	0.5	–	4	μ s
		IDLE 1, 2 mode				
		SLOW 1, 2 mode	117.6	–	133.3	
		SLEEP 1, 2 mode				
High Level Clock Pulse Width	twcH	For external clock operation (XIN input) fc = 8 MHz	–	62.5	–	ns
Low Level Clock Pulse Width	twcL					
High Level Clock Pulse Width	twcH	For external clock operation (XTIN input) fc = 32.768 kHz	–	15.26	–	μ s
Low Level Clock Pulse Width	twcL					

(V_{SS} = 0 V, V_{DD} = 1.8 to 2.7 V, Topr = – 40 to 85°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Machine Cycle Time	tcy	NORMAL 1, 2 mode	0.95	–	4	μ s
		IDLE 1, 2 mode				
		SLOW 1, 2 mode	117.6	–	133.3	
		SLEEP 1, 2 mode				
High Level Clock Pulse Width	twcH	For external clock operation (XIN input)	–	119.05	–	ns
Low Level Clock Pulse Width	twcL	fc = 4.2 MHz				
High Level Clock Pulse Width	twcH	For external clock operation (XTIN input)	–	15.26	–	μ s
Low Level Clock Pulse Width	twcL	fc = 32.768 kHz				

Timer Counter 1 input (ECIN) Characteristics

(V_{SS} = 0 V, Topr = – 40 to 85°C)

Parameter	Symbol	Condition		Min	Typ.	Max	Unit
TC1 input (ECIN input)	t _{TC1}	Frequency measurement mode V _{DD} = 4.5 to 5.5 V	Single edge count	–	–	16	MHz
		Frequency measurement mode V _{DD} = 2.7 to 4.5 V	Single edge count	–	–	8	
		Frequency measurement mode V _{DD} = 1.8 to 2.7 V	Single edge count	–	–	4.2	

Recommended Oscillating Conditions - 1

(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, T_{opr} = – 40 to 85°C)

PARAMETER	Oscillator	Oscillation Frequency	Recommended Oscillator	Recommended Constant	
				C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	16 MHz	MURATA CSA16.00MXZ040	10 pF	10 pF
		8 MHz	MURATA CSA8.00MTZ CST8.00MTW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)
		4.19 MHz	MURATA CSA4.19MG CST4.19MGW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)
Low-frequency Oscillation	Crystal Oscillator	32.768 kHz	SII VT-200	6 pF	6 pF

Recommended Oscillating Conditions - 2

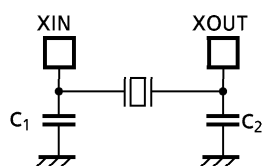
(V_{SS} = 0 V, V_{DD} = 2.7 to 5.5 V, T_{opr} = – 40 to 85°C)

PARAMETER	Oscillator	Oscillation Frequency	Recommended Oscillator	Recommended Constant	
				C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	8 MHz	MURATA CSA8.00MTZ CST8.00MTW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)
		4.19 MHz	MURATA CSA4.19MG CST4.19MGW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)

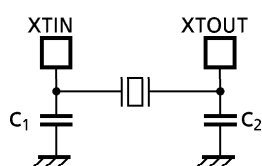
Recommended Oscillating Conditions - 3

(V_{SS} = 0 V, V_{DD} = 1.8 to 5.5 V, T_{opr} = – 40 to 85°C)

PARAMETER	Oscillator	Oscillation Frequency	Recommended Oscillator	Recommended Constant	
				C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	4.19 MHz	MURATA CSA4.19MG CST4.19MGW	30 pF 30 pF (built-in)	30 pF 30 pF (built-in)



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

Note 1: Use of a quartz oscillator for high-frequency oscillation is allowed only when V_{DD} is 2.7 V or higher. When V_{DD} is lower than 2.7 V, use a ceramic resonator.

Note 2: To ensure stable oscillation, the resonator position, load capacitance, etc. must be appropriate. Because these factors are greatly affected by board patterns, please be sure to evaluate operation on the board on which the device will actually be mounted.

Note 3: An electrical shield by metal shield plate on the surface of IC package is recommended in order to protect the device from the high electric field stress applied from CRT (Cathodic Ray Tube) for continuous reliable operation.

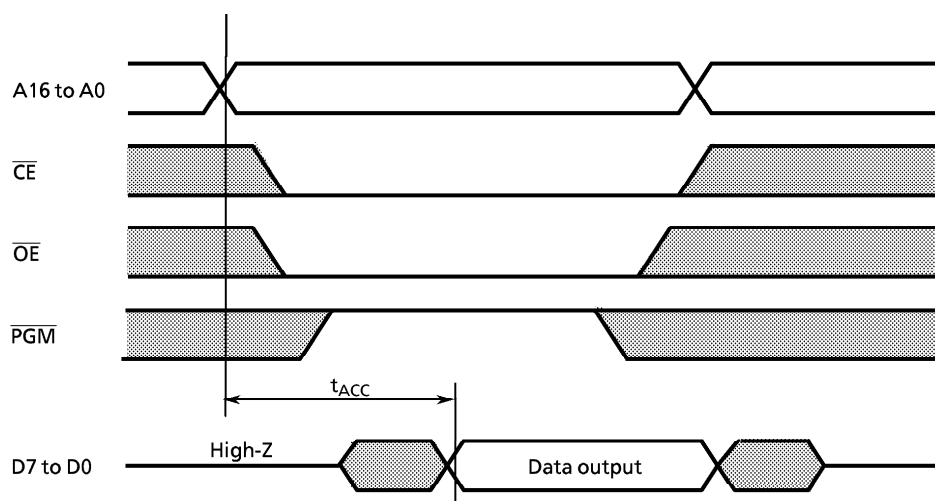
Note 4: The product numbers and specifications of the resonators by Murata Manufacturing Co., Ltd. are subject to change. For up-to-date information, please refer to the following URL;
<http://www.murata.co.jp/search/index.html>

DC Characteristics, AC Characteristics (PROM Mode) ($V_{SS} = 0\text{ V}$, $T_{opr} = -40\text{ to }85^{\circ}\text{C}$)

(1) Read operation in PROM mode

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
High level input voltage (TTL)	V _{IH4}		2.2	–	V _{CC}	V
Low leve input voltage (TTL)	V _{IL4}		0	–	0.8	
Power supply	V _{CC}		4.75	5.0	5.25	
Power supply of program	V _{PP}					
Address access time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	–	1.5t _{cyc} + 300	–	ns

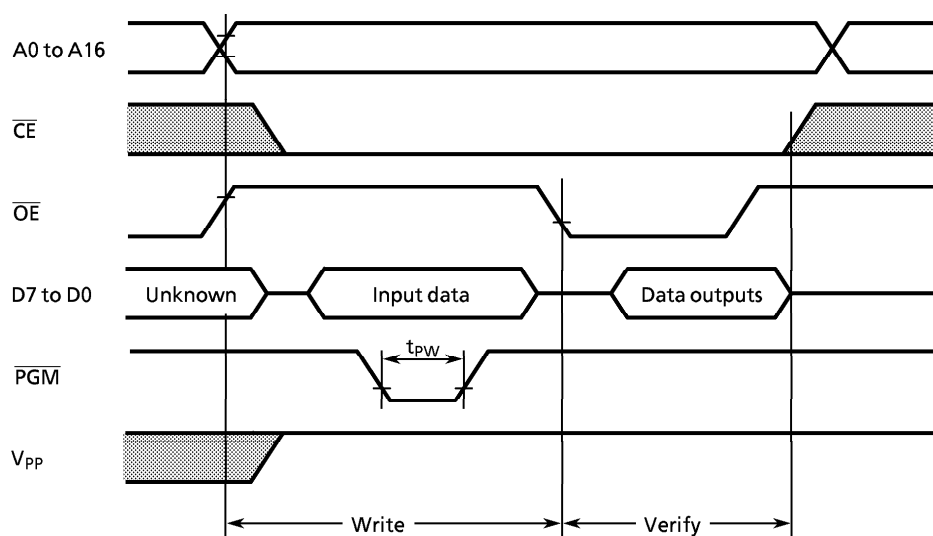
Note: $t_{cyc} = 500\text{ ns}$ at 8 MHz



(2) Program operation (High-speed) ($T_{opr} = 25 \pm 5^\circ\text{C}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
High level input voltage (TTL)	V_{IH4}		2.2	–	V_{CC}	V
Low level input voltage (TTL)	V_{IL4}		0	–	0.8	
Power supply	V_{CC}		6.0	6.25	6.5	
Power supply of program	V_{PP}		12.5	12.75	13.0	
Pulse width of initializing program	t_{PW}	$V_{CC} = 6.0\text{ V}$	0.095	0.1	0.105	ms

High-speed program writing



Note 1: The power supply of V_{PP} (12.75 V) must be set power-on at the same time or the later time for a power supply of V_{CC} and must be clear power-on at the same time or early time for a power supply of V_{CC} .

Note 2: The pulling up/down device on the condition of $V_{PP} = 12.75\text{ V} \pm 0.25\text{ V}$ causes a damage for the device. Do not pull up/down at programming.

Note 3: Use the recommended adapter (see 1.2.2 (1)) and mode (see 1.2.2 (3) i). Using other than the above condition may cause the trouble of the writing.